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Vishay Semiconductors

High Speed Infrared Emitting Diodes, 850 nm, GaAlAs, DH



DESCRIPTION

VSMG2000X01 series are infrared, 850 nm emitting diodes in GaAlAs (DH) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

FEATURES

- Package type: surface-mount
- · Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- AEC-Q101 qualified
- Peak wavelength: λ_p = 850 nm
- High reliability
- · High radiant power
- · High radiant intensity
- Angle of half intensity: $\varphi = \pm 12^{\circ}$
- Low forward voltage
- · Suitable for high pulse current operation
- Terminal configurations: gullwing or reserve gullwing
- Package matches with detector VEMD2000X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- IrDA compatible data transmission
- IR-illumination (CCTV)
- · Miniature light barrier
- Photointerrupters
- · Optical switch
- Shaft encoders
- IR emitter source for proximity applications

PRODUCT SUMMARY				
COMPONENT	I _e (mW/sr)	φ (deg)	$\lambda_{\mathbf{p}}$ (nm)	t _r (ns)
VSMG2000X01	40	± 12	850	20
VSMG2020X01	40	± 12	850	20

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMG2000X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMG2020X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

Note

· MOQ: minimum order quantity











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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	5	V
Forward current		I _F	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA
Surge forward current	t _p = 100 μs	I _{FSM}	1	А
Power dissipation		P _V	170	mW
Junction temperature		T _j	100	°C
Operating temperature range		T _{amb}	- 40 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	Acc. figure 9, J-STD-020	T _{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	250	K/W

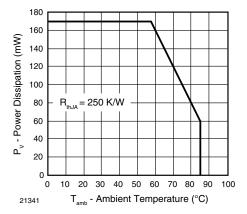


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

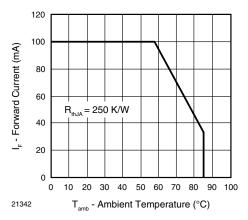


Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}	1.25	1.45	1.7	V
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	V_{F}		2.3		V
Temperature coefficient of V _F	I _F = 1 mA	TK_{VF}		- 1.8		mV/K
	I _F = 100 mA	TK _{VF}		- 1.1		mV/K
Reverse current	V _R = 5 V	I _R			10	μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ		125		pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	20	40	60	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	l _e		350		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	φ _e		40		mW
Temperature coefficient of φ _e	I _F = 100 mA	TΚφ _e		- 0.35		%/K
Angle of half intensity		φ		± 12		deg
Peak wavelength	I _F = 30 mA	λ_{p}	830	850	870	nm
Spectral bandwidth	I _F = 30 mA	Δλ		35		nm
Temperature coefficient of λ_p	I _F = 30 mA	TKλ _p		0.25		nm/K
Rise time	I _F = 100 mA, 20 % to 80 %	t _r		20		ns
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		20		ns
Cut-off frequency	I _{DC} = 70 mA, I _{AC} = 30 mA pp	f _c		23		MHz
Virtual source diameter		d		1.5		mm

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

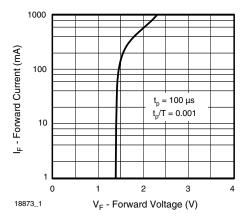


Fig. 3 - Forward Current vs. Forward Voltage

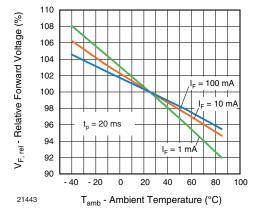


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

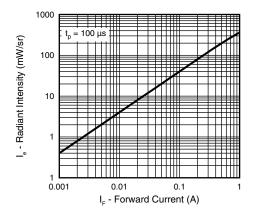


Fig. 5 - Radiant Intensity vs. Forward Current

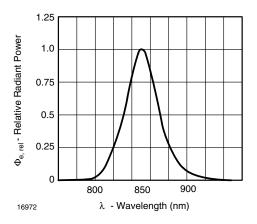


Fig. 6 - Relative Radiant Power vs. Wavelength

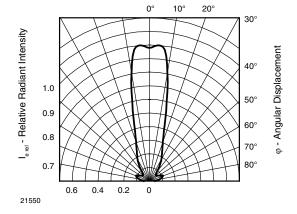


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

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SOLDER PROFILE

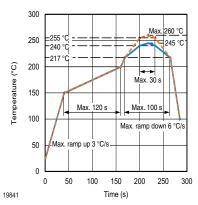


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

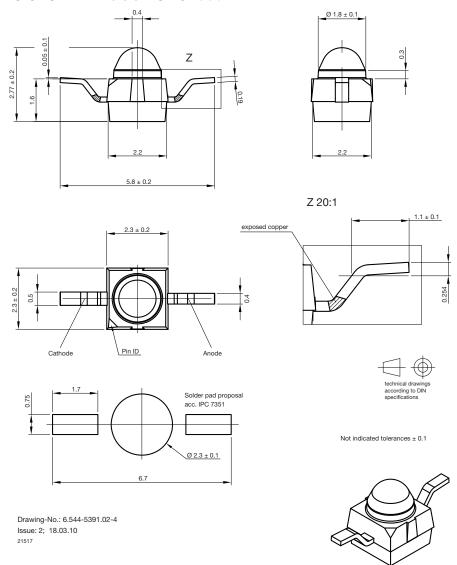
Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 2a, acc. to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.

PACKAGE DIMENSIONS in millimeters: **VSMG2000**

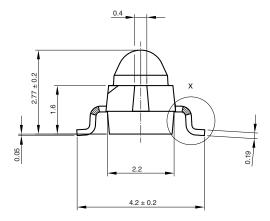


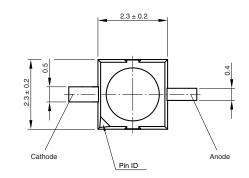


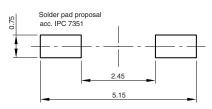
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PACKAGE DIMENSIONS in millimeters: VSMG2020

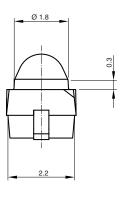
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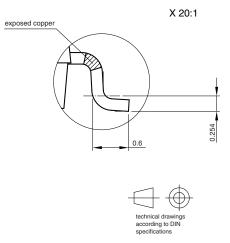




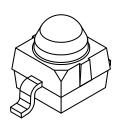


Drawing-No.: 6.544-5383.02-4 Issue: 4; 18.03.10 21488





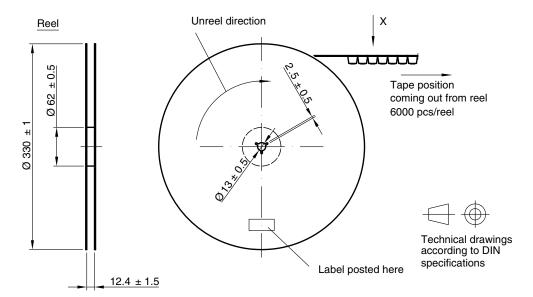
Not indicated tolerances ± 0.1



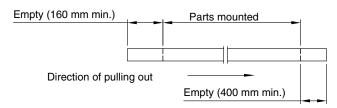


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TAPING AND REEL DIMENSIONS in millimeters: VSMG2000

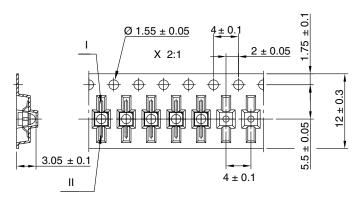


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II
VEMT2000		
VEMT2500	Collector	Emitter
VEMD2000		
VEMD2500	0-4	AI -
VSMB2000	Cathode	Anode
VSMG2000		
VSMY2850RG	Anode	Cathode



Drawing-No.: 9.800-5100.01-4

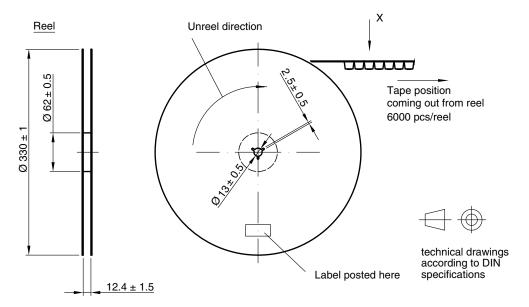
Issue: 2; 18.03.10

21572

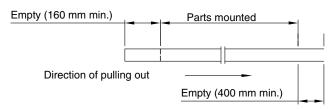


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TAPING AND REEL DIMENSIONS in millimeters: VSMG2020

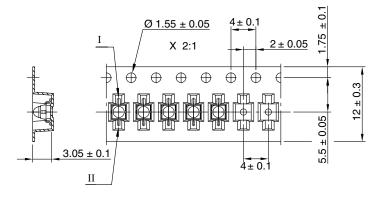


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II
VEMT2020		
VEMT2520	Collector	Emitter
VSMB2020		
VSMG2020	0-44-	Al -
VEMD2020	Cathode	Anode
VEMD2520		
VSMY2850G	Anode	Cathode



Drawing-No.: 9.800-5091.01-4

Issue: 3; 18.03.10

21571

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